P.Walter U-2-02 81788.0025

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of

Art Unit:

2002.

2814

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Examiner: Seiichi Mori

WEISS, H.

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Office, Fex No. 703-308-7722 on March 21,

March 22, 2002

MAR 2 1 2002

TECHNOLOGY CENTER 2800

Serial No.: 09/451.619

Filed: November 30, 1999

NON-VOLATILE SEMICONDUCTOR For:

MEMORY HAVING A DECREASED GATE

LENGTH AND MANUFACTURING METHOD THEREOF (As Amended)

LETTER TO THE OFFICIAL DRAFTSPERSON

Assistant Commissioner for Patents

Washington, D.C. 20231 Attention: Amendment

Dear Sir:

Applicant respectfully requests approval of two (2) sheets of proposed drawings changes with changes to Figures 1 and 5 shown in red ink. Applicant respectfully submits proposed changes to Figures 1 and 5 changing reference character "7" to reference character "8" for the source region in Figure 1 and incorporating the legend "Prior Art" in Figure 5. No new matter has been added.

Respectfully submitted,

HOGAN & HARTSON, L.L.P

Date: March 22, 2002

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